

# Materials department: superficial research in depth

S. Castellanos, R. Bliem, B. Weber, J. Frenken  
2019 Source Workshop, Amsterdam, 4th Nov



## Nanolayers

Joost Frenken

pellicle optics

## Contact dynamics

Bart Weber

wafer/wafer table

# Materials department

## EUV Photoresists

Sonia Castellanos

resists

## Materials & Surface Science for EUVL

Roland Bliem

pellicle optics wafer/WT resists

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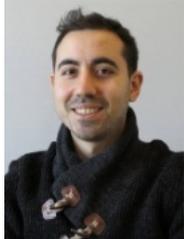
Roland Bliem

pellicle optics wafer/WT resists

## PhD students



Cristina Sfiligoj



Görsel Yetik



Victor Vollema

## Senior staff



Joost Frenken



Jan Verhoeven

## Technician



Arend-Jan  
van Calcar

## TOPICS & TECHNIQUES

### Thin-film deposition

- Structure, texture, roughness, ...
- Relation to deposition method (e.g. sputtering...)

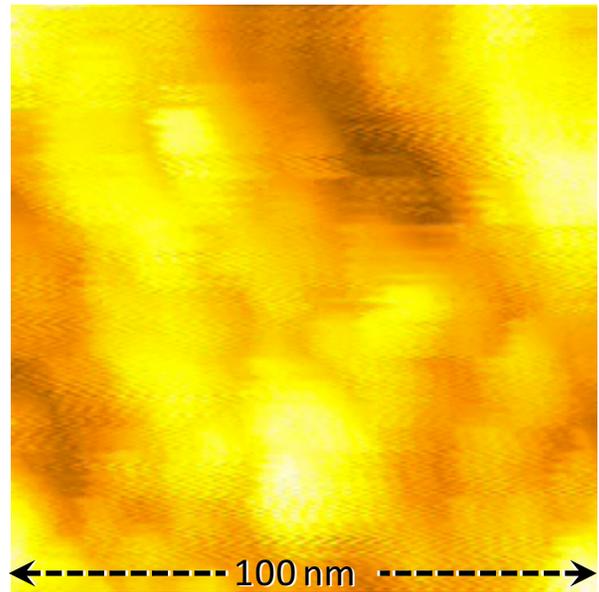
### Thin-film evolution

- Thermal effects
- Influence of H<sub>2</sub> and H, ...

### Techniques

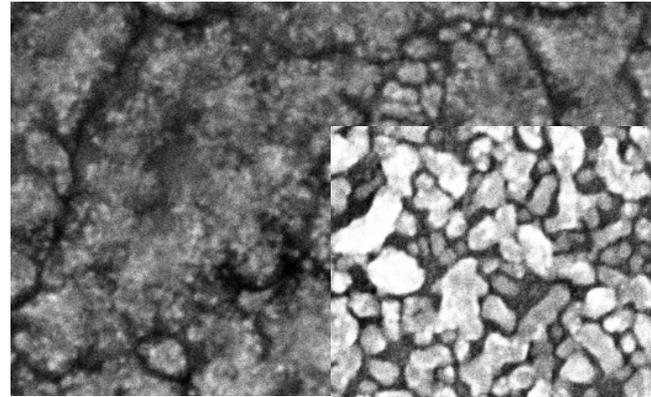
- Various deposition techniques (e-beam, sputter)
- STM (in situ), AFM, SEM, Surface stress (in situ)
- XPS

People: Cristina Sfiligoj (PhD stud.), Victor Vollema (PhD stud.)  
Goals: (i) deposition-STM operational, (ii) observe polycrystallinity and dewetting



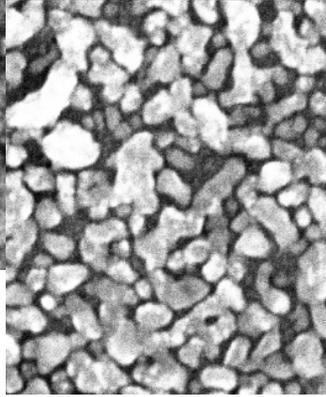
Live STM: 6 nm Ru deposition (e-beam) on Si, 122 min, room temp,  $5 \times 10^{-9}$  mbar

- Depo-STM operational
- Ru forms grains from the start



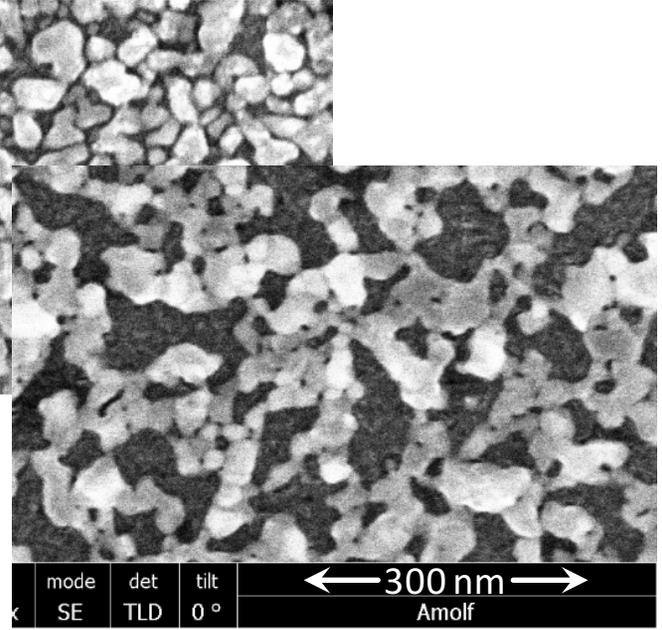
5 nm high-density Ru, after 800°C

- Severe Ru dewetting at high T
- Film density has influence



5 nm low-density Ru, after 800°C

SEM-images: sputter-deposited Ru on SiO<sub>2</sub> after annealing



2 nm low-density + 3 nm high-density Ru, after 800°C

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## Group Members



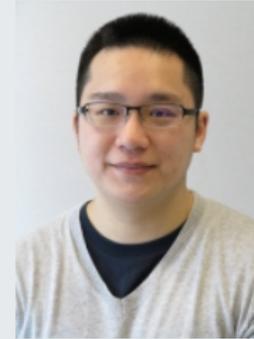
**prof.dr. Steve Franklin**  
Group leader



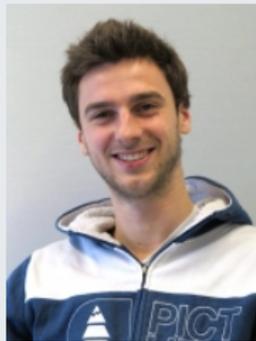
**dr. Bart Weber**  
Group leader



**dr. Fiona Elam**  
Postdoc



**Feng-Chun Hsia**  
PhD student



**Cyrian Leriche**  
Intern

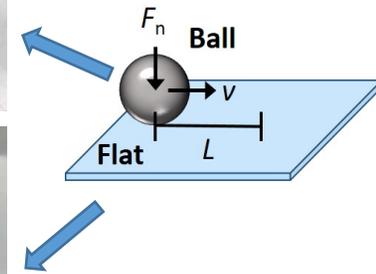
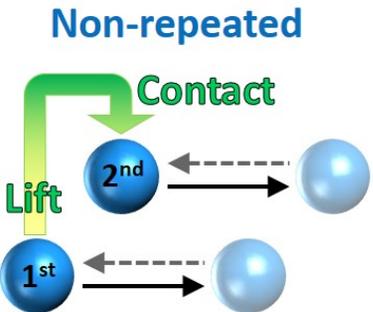
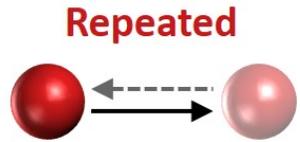
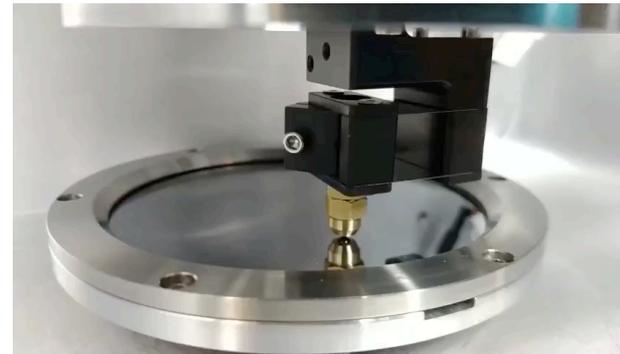
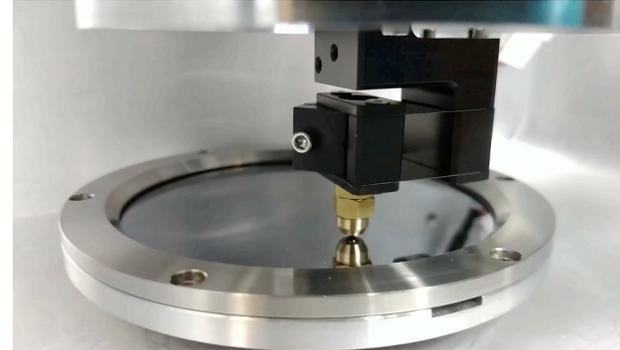
+PhD    +PD

# Repeated and non-repeated sliding:

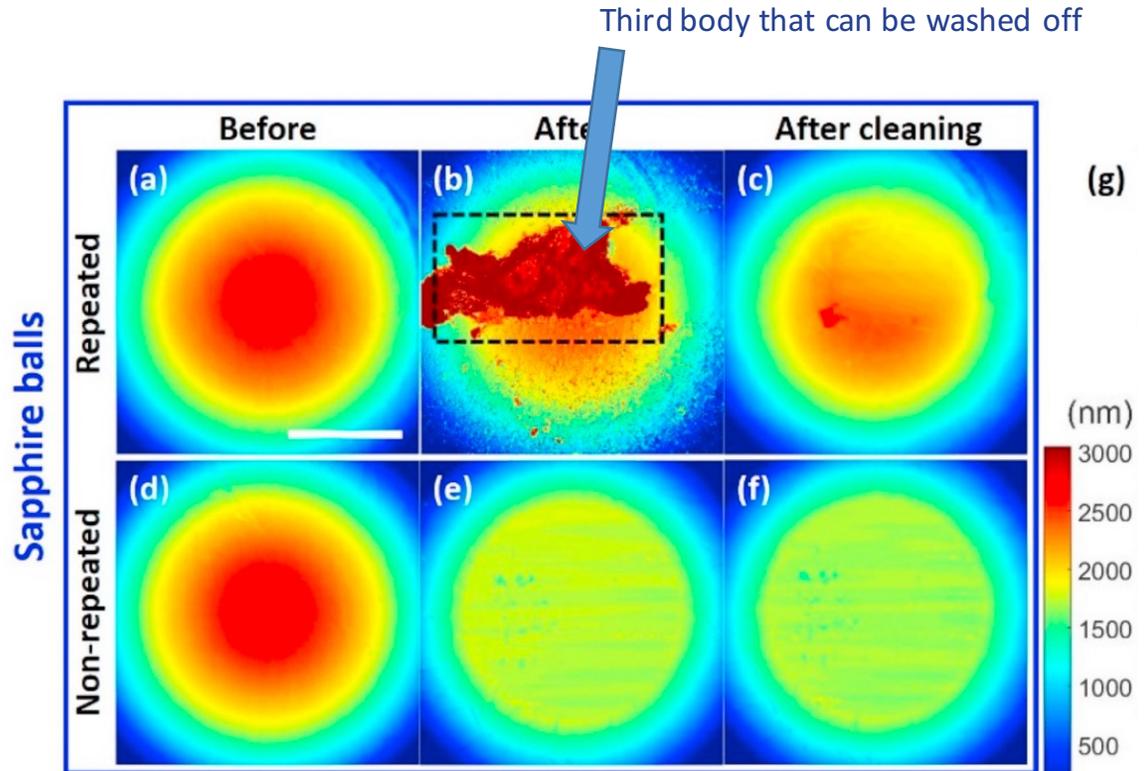
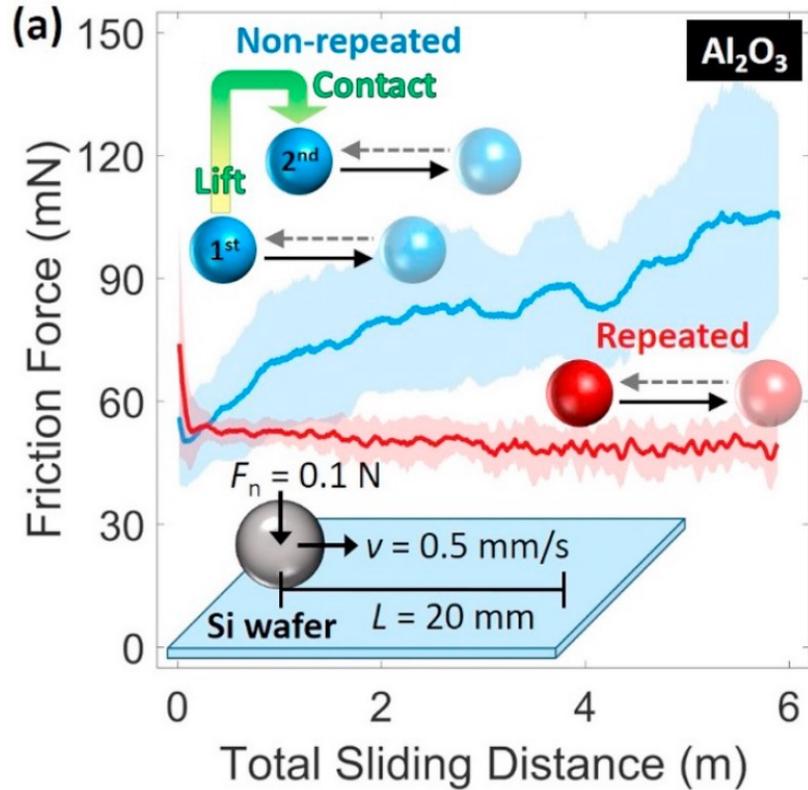
Example



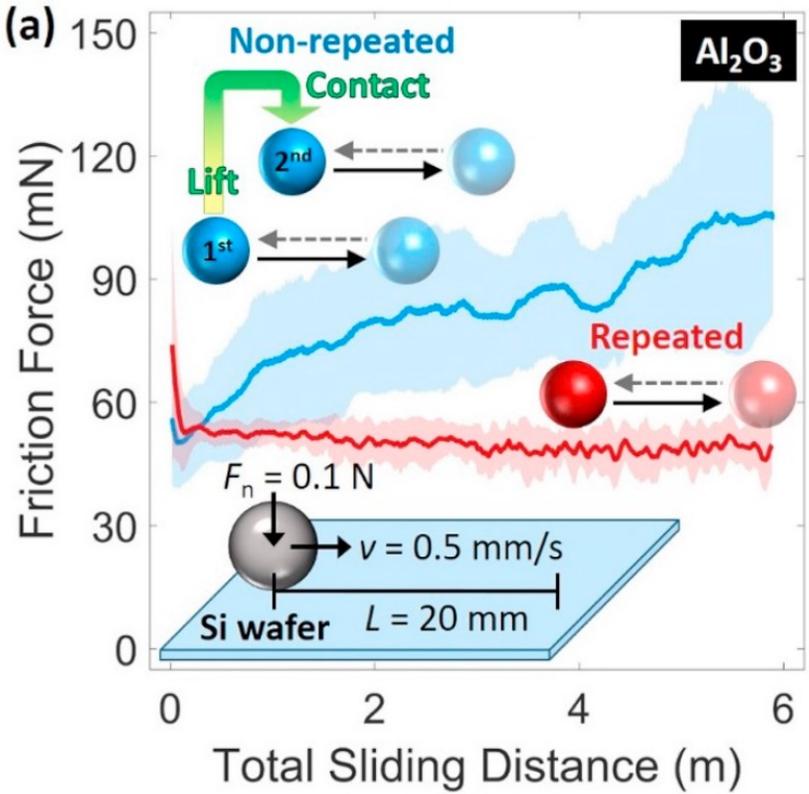
ARCNL Experiment



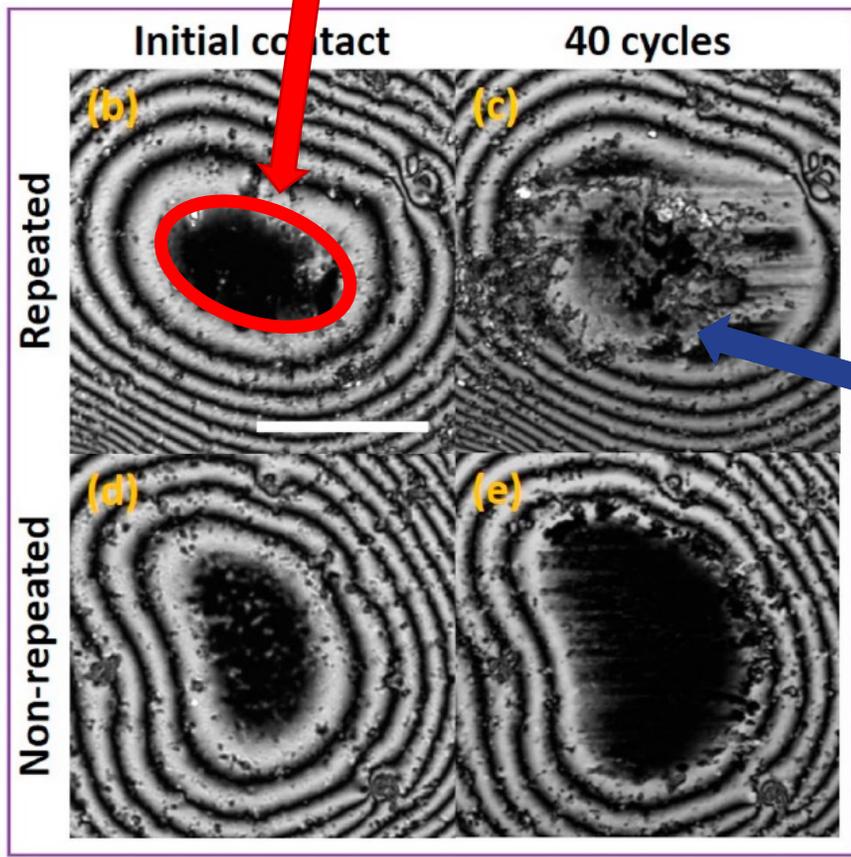
# Non-repeated: 2x more friction, 6x wear



# Third body = compressed debris



Ball-on-flat contact within central interference fringe



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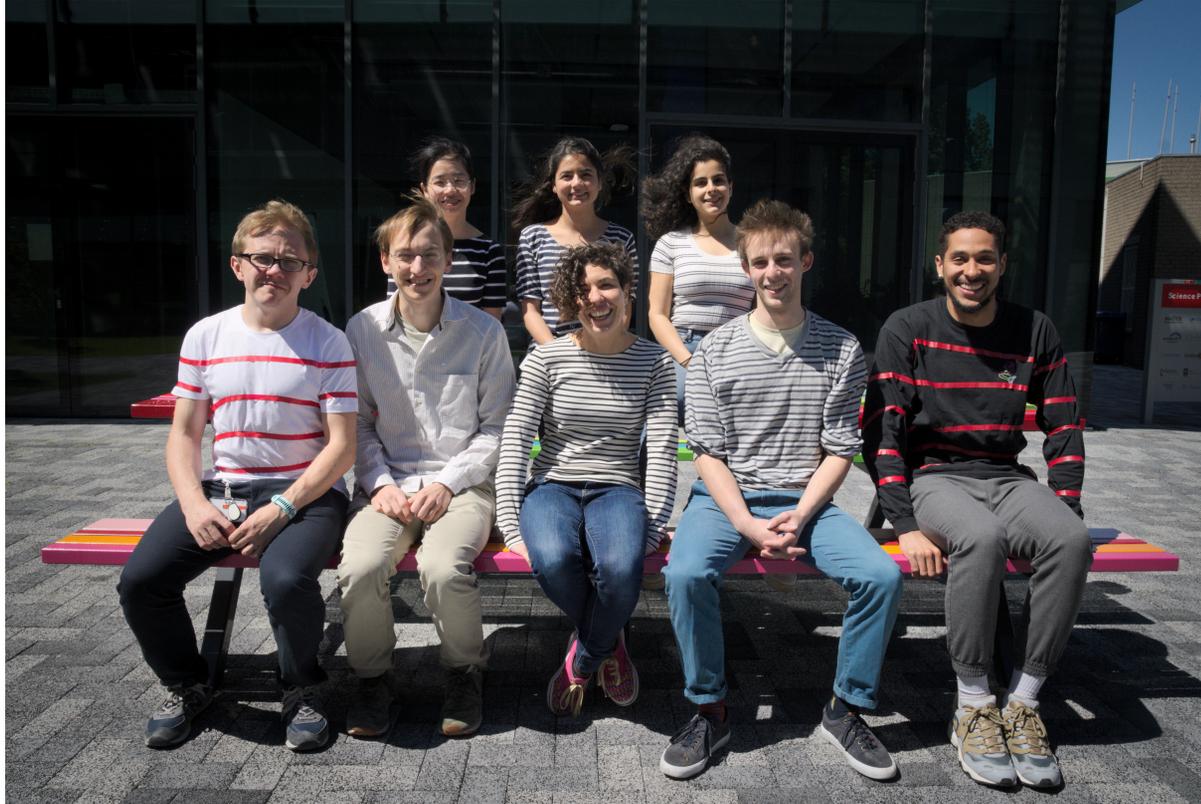
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# EUV Photoresists: team

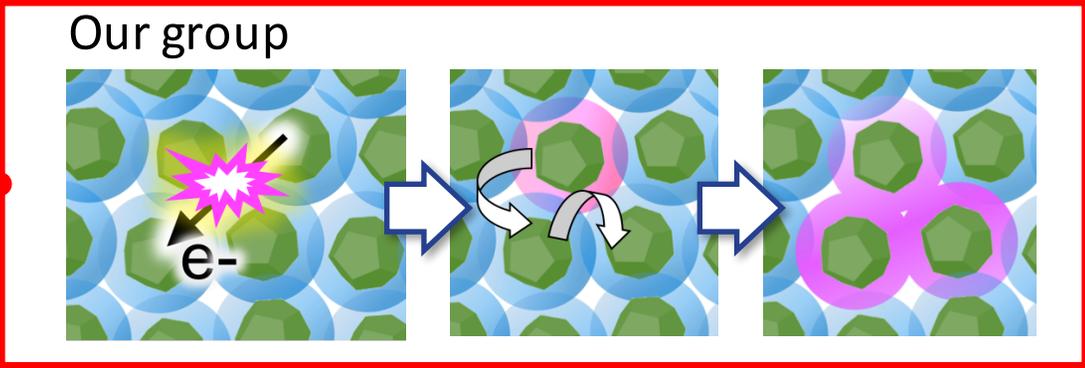
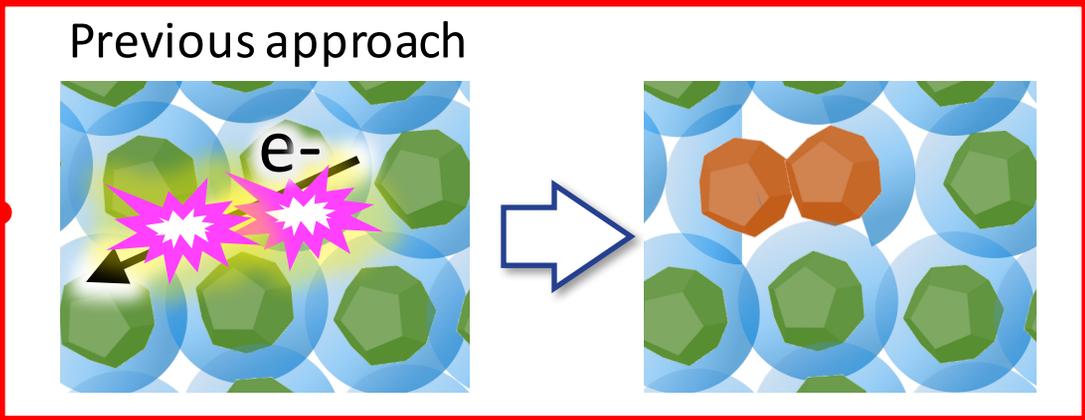
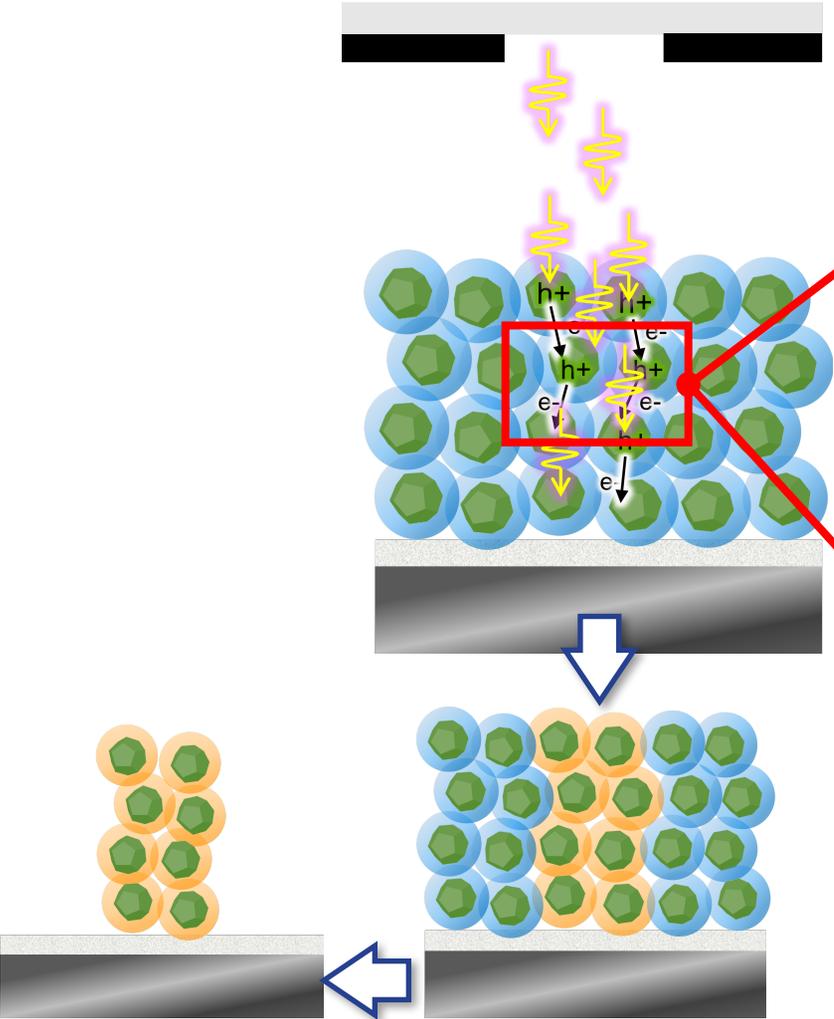


PAUL SCHERRER INSTITUT



Elettra Sincrotrone Trieste



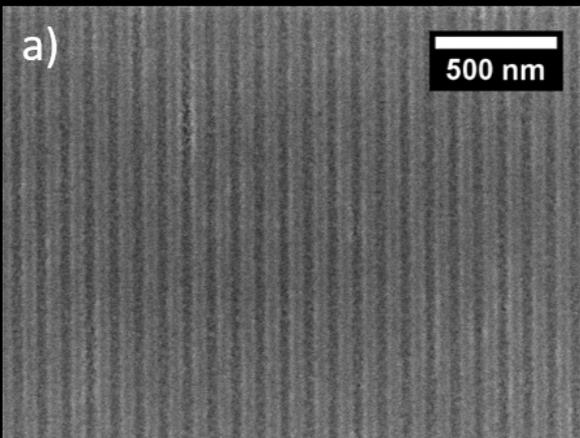


*J. Micro/Nanolith. MEMS MOEMS* 18(1), 013504, 2019  
*J. Mater. Chem. C*, 7, 33, 2019  
*Eur. J. Inorg. Chem.*, 4136, 2019  
*Proc. SPIE* 10957, 2019, 109570B  
*J. Nano/Microlitho. MEMS MOEMS* (in press)

## 1st generation

HP 50 nm  
57 mJ/cm<sup>2</sup>

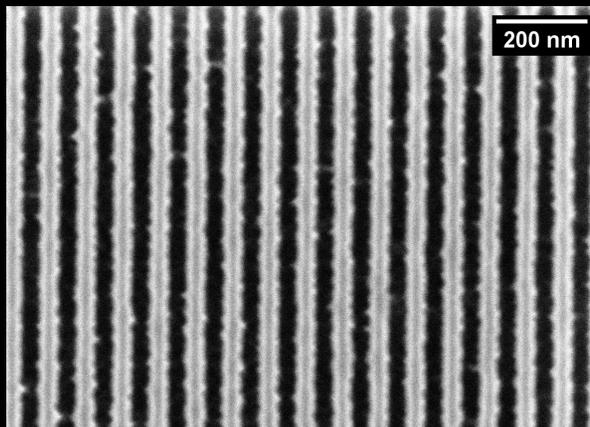
Zr-MOC



## 2nd generation

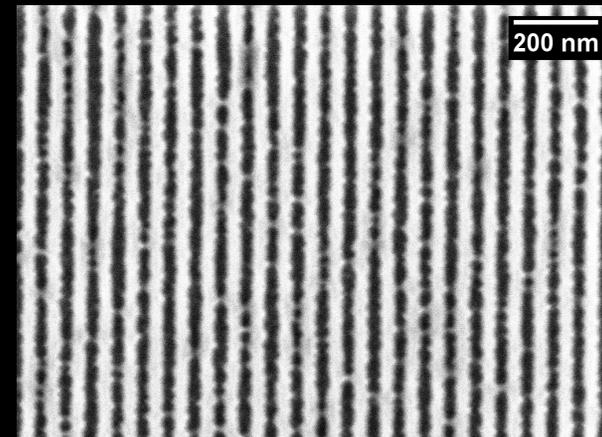
HP 40 nm  
38 mJ/cm<sup>2</sup>

Zr-MOC-F



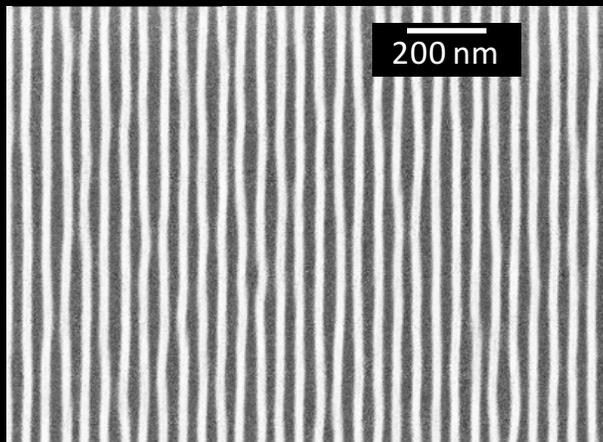
HP 30 nm  
36 mJ/cm<sup>2</sup>

Zr-MOC-F



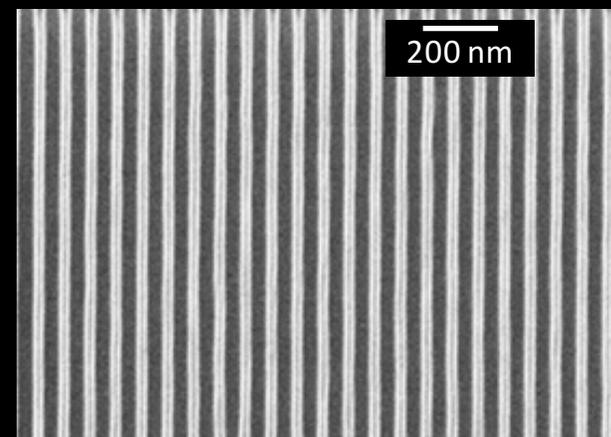
HP 22 nm  
13 mJ/cm<sup>2</sup>

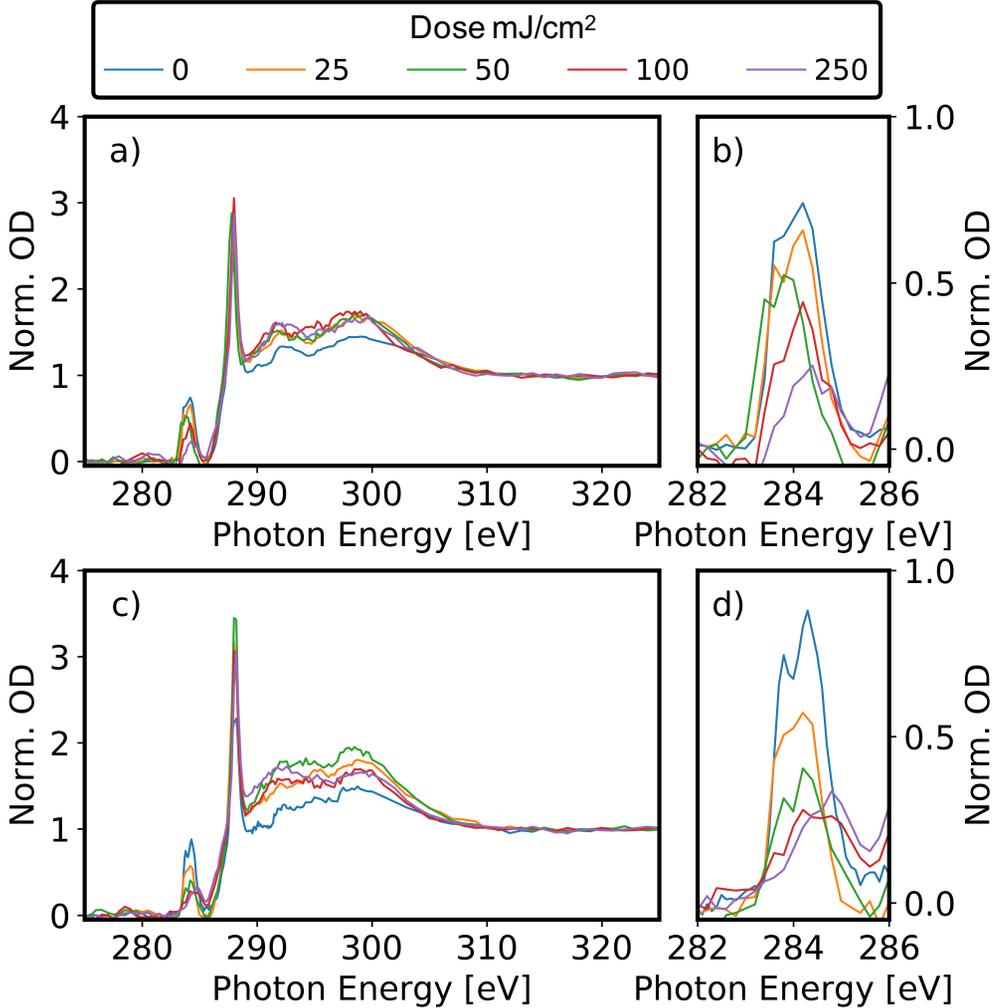
Zn-MOC-F



HP 30 nm  
15 mJ/cm<sup>2</sup>

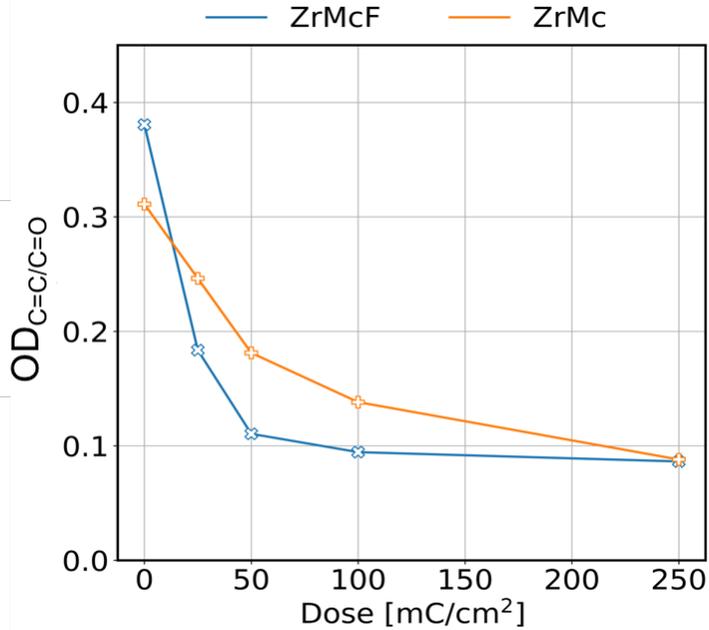
Zn-MOC-F





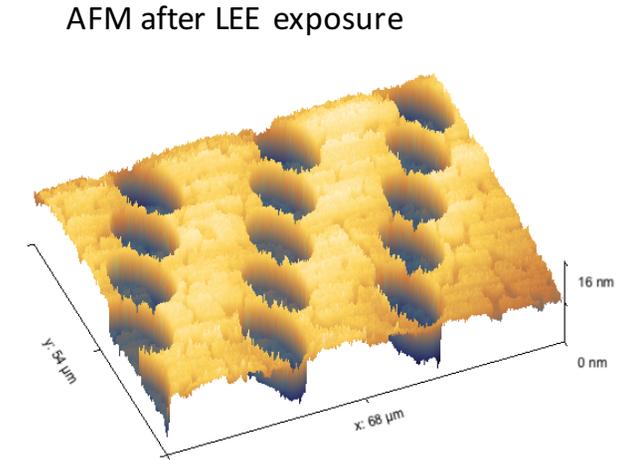
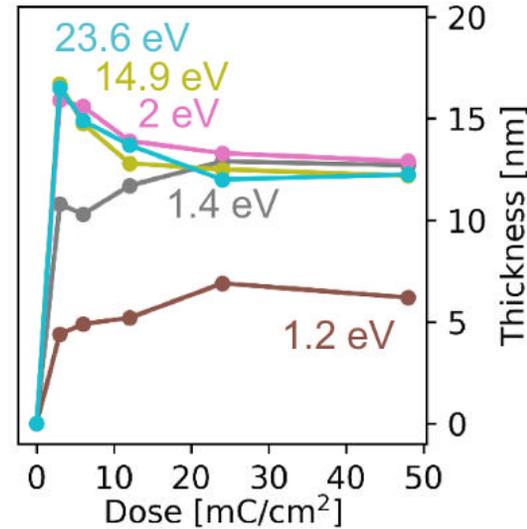
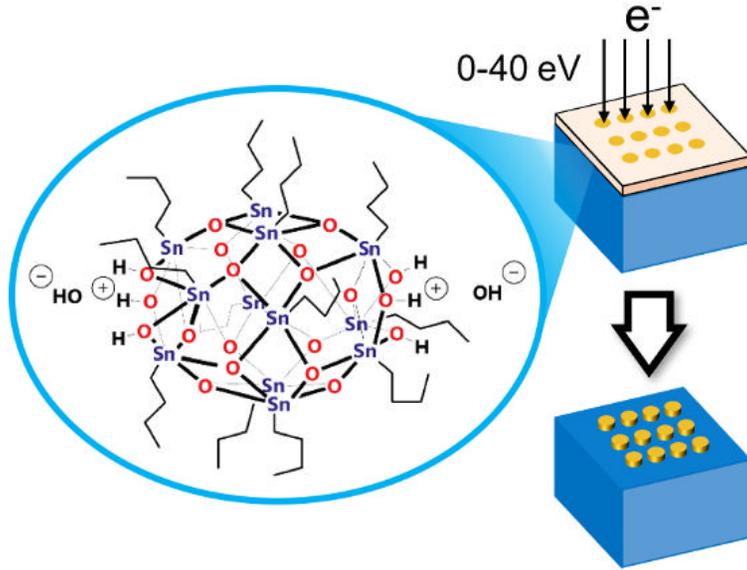
Spectroscopy research:

- new mechanisms vs litho performance
- Reaction kinetics vs sensitivity/contrast



Chemistry of low-energy electrons:

- $< 10$  e-/molecule for patterning
- $e < 2$  eV do chemistry



I. Bespalov, Y. Zhang, R. M. Tromp, S.J. van der Molen, A. M. Brouwer, J. Jobst\*, S. Castellanos\*, "The Key Role of Very Low-Energy Electrons in Tin-based Molecular Resists for Extreme Ultraviolet Nanolithography" (**submitted**)

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Alessandro Troglia



Stefan van Vliet

## Technician



Bartjan  
Spaanderman

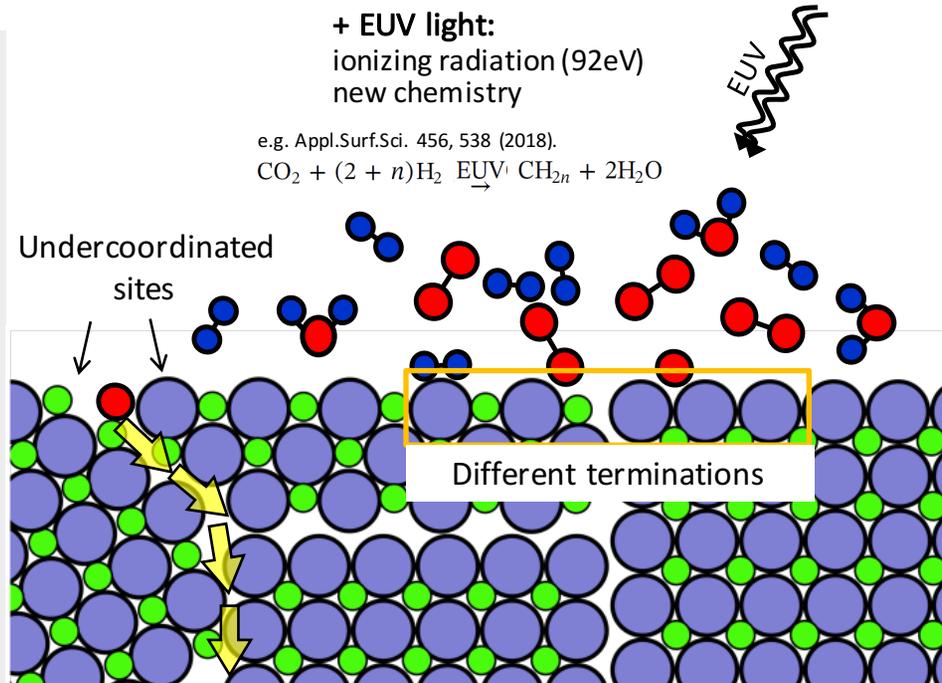
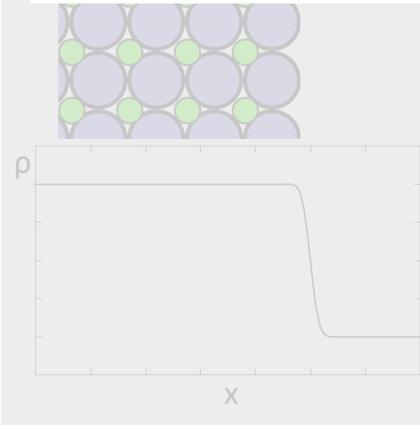
## Senior staff



Roland Bliem

## Surfaces & Interfaces: Locations of sharp gradients

Real life:  
not a border to vacuum  
not a perfect crystal  
not a static situation



Grain boundaries = diffusion channels (+ reactive spots, breaking points, nucleation points ...)

- Central aim: Understand fundamental interaction processes at surfaces while they are happening

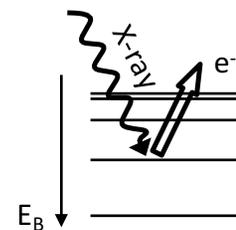
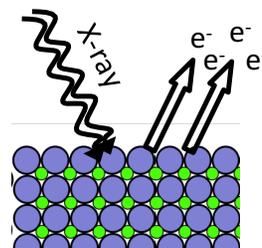
- Surface  
+ gas environment  
+ EUV radiation, + ...

- Tool: (Near-ambient pressure)

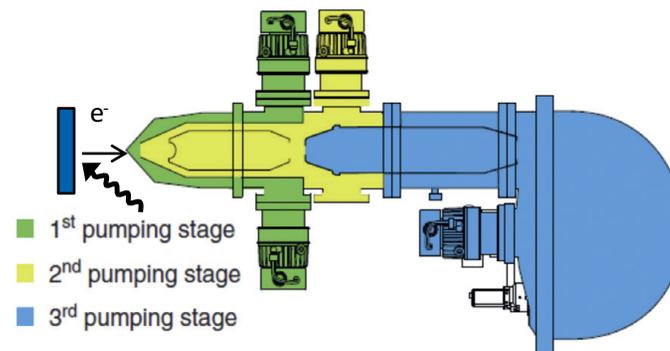
## X-ray Photoelectron Spectroscopy (NAP)-XPS

- Surface-sensitive & Quantitative
- Composition and chemical state
- Combined with extreme ultraviolet (EUV) light source (92 eV, 13.5 nm)
- *In-situ* XPS at up to 20 mbar

→ at the relevant conditions

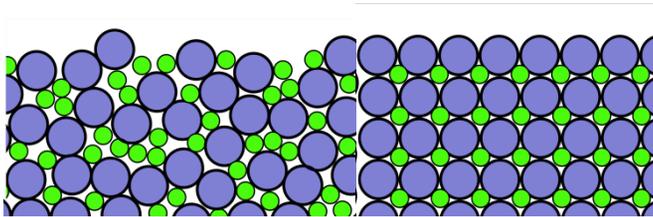


$$E_{\text{kin}} = E_{\text{ph}} - E_{\text{B}} - \Phi$$



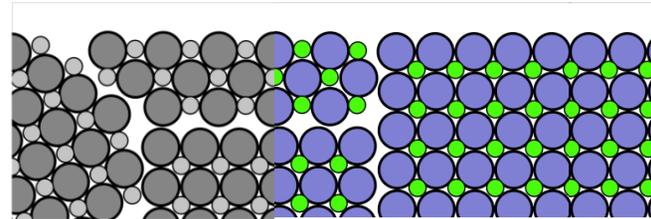
## Composition

Alloying, Doping, New Materials



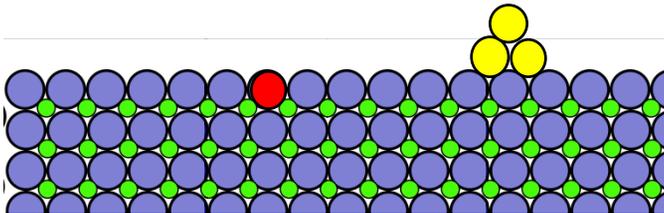
## Structure

Perfect - polycrystalline - disordered



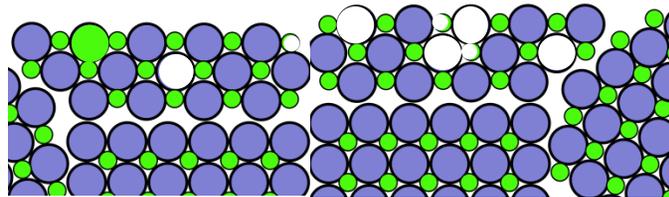
## Defectiveness

Vacancies, Boundaries, Steps, Substitution



## Contaminants

Minority species can dominate chemical processes at the surface (e.g. Ru+Sn)



- Nature's preference: crystallization  
→ (poly-)crystalline films for most deposition methods
- Pulsed Laser Deposition (PLD)  
Complex crystalline layers  
but also off-equilibrium structures  
→ Saturating surface with material at every pulse  
→ Flexible in composition

